

UNITED STATES DEPARTMENT OF COMMERCE Patent and Trademark Office

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Serial Number	FILING DAVE	First Mamei	attorney docket no.		
07/697,830	05/09/91	HUANG	J	35441	
				examiner	
			LOKE,S		
RICHARD M. 9 RAYTHEON COM	- · · · · · · · · · · · · · · · · · · ·		ART UNI	PAPER NUMBER	
PATENT DEPAR	STREET		2508	2	
LEXINGTON, N		F	Date Mailed:	10/29/91	

This is a communication from the examiner in charge of your application.

C	المالاذ	4155	SIONER OF PATENTS AND TRADEWARE	KS								
×	This	s ap	pplication has been examined	☐ Responsive to commun	nication file	d on	[This action is made final.				
	A shortened statutory period for response to this action is set to expire month(s), days from the date of this letter. Failure to respond within the period for response will cause the application to become abandoned. 35 U.S.C. 133											
Part I			THE FOLLOWING ATTACHMENT(S) ARE PART OF THIS ACTION:									
3	i. (i. (i. (Notice of References Cited by Exam Notice of Art Cited by Applicant, PT Information on How to Effect Drawin	O-1449.	lotice of inform	Patent Drawing, PTO-948. I informal Patent Application, Form PTO-152.						
Part	11		SUMMARY OF ACTION									
1	. ,	×	Claims	1-6				are pending in the application.				
			Of the above, claims				are	withdrawn from consideration.				
2	. [Claims					have been cancelled.				
3	. [Claims					are allowed.				
4			Claims									
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е	_	_						•				
7	. L		This application has been filed with informal drawings under 37 C.F.R. 1.85 which are acceptable for examination purposes.									
. 8	. [Formal drawings are required in response to this Office action.									
9	. [The corrected or substitute drawings have been received on Under 37 C.F.R. 1.84 these drawings are acceptable. In not acceptable (see explanation or Notice re Patent Drawing, PTO-948).									
10	. [The proposed additional or substitute sheet(s) of drawings, filed on has (have) been approved by the examiner disapproved by the examiner (see explanation).									
11	. [The proposed drawing correction, fil	led on,	has been	approved.	☐ disappro	oved (see explanation).				
12	. [Acknowledgment is made of the claim for priority under U.S.C. 119. The certified copy has 🔲 been received 🧖 not been received									
			been filed in parent application,	serial no.		; filed on						
13	. [Since this application appears to be in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11; 453 O.G. 213.									
14	. [\supset	Other									

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The following is a quotation of the first paragraph of 35 U.S.C. § 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

The specification is objected to under 35 U.S.C. § 112, first paragraph, as the specification, as originally filed, does not provide support for the invention as is now claimed. The specification (P,18, line 12-15) and Fig.2 disclose a dopant spike layer [59] formed on the channel layer having a few angstroms thickness and having a dopant concentration. However, the specification never discloses the dopant spike layer formed inside the channel layer [20].

Claims 5-6 are rejected under 35 U.S.C. § 112, first paragraph, for the reasons set forth in the objection to the specification.

Claims 2 and 4-6 are rejected under 35 U.S.C. § 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 2, line 4, it is unclear why "a" is used after the word "material".

In claim 4, line 3, is the first charge screen layer being

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referred to the 3rd portion of the charge donor layer?

In claim 5, "said charge donor layer" and "said second Group III-V material" have no antecedent basis. In line 19, what is "a/cc"?

The following is a quotation of the appropriate paragraphs of 35 U.S.C. § 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -(b) the invention was patented or described in a printed
publication in this or a foreign country or in public use or
on sale in this country, more than one year prior to the
date of application for patent in the United States.

Claims 1 and 3 are clear and definite, 2 and 4-6 insofar, as in compliance with 35 USC 112 are rejected under 35 U.S.C. § 102(b) as being clearly anticipated by Smith et al.

Smith et al discloses a high electron mobility transistor (HFET) in fig.1. It comprises:

- (a) a GaAs substrate;
- (b) an In GaAs channel layer disposed over the substrate;
- (c) a charge donor region (1st charge screen layer) comprised of a 1st region of undoped $Al_{0.25}$ $Ga_{0.75}$ AS having a bandgap higher than the bandgap of the channel layer, a planar doping layer having a dopant concentration of 5×10^{12} cm⁻² Si and a n type $Al_{0.25}$ $Ga_{0.75}$ AS
- (d) a pair of n+ GaAs contact regions disposed over the 1st charge screen layer;
- (e) a gate electrode disposed in the n type $Al_{0.25}$ $Ga_{0.75}$ AS

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(f) a pair of source and drain electrodes contact with the n+GaAs contact regions.

Any inquiry concerning this communication should be directed to Loke at telephone number (703) 308-4920.

Loke/dm October 24, 1991

ROLP HILLE
SUPERVISORY PATENT EXAMINER
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